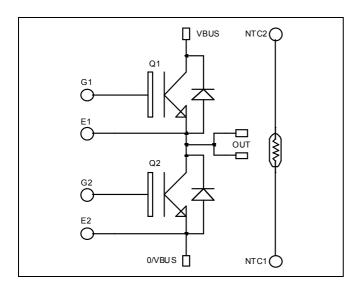


Phase leg NPT IGBT Power Module





E2 🛭

E2 0

O/VBUS

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS compliant

Absolute maximum ratings

VBUS

0

| Symbol | Parameter | | Max ratings | Unit |
|-----------|---------------------------------------|------------------------|-------------|------|
| V_{CES} | Collector - Emitter Breakdown Voltage | | 600 | V |
| ī | Continuous Collector Current | $T_c = 25^{\circ}C$ | 220 | |
| I_{C} | Continuous Collector Current | $T_c = 80$ °C | 180 | A |
| I_{CM} | Pulsed Collector Current | $T_c = 25^{\circ}C$ | 630 | |
| V_{GE} | Gate – Emitter Voltage | | ±20 | V |
| P_{D} | Maximum Power Dissipation | $T_c = 25^{\circ}C$ | 833 | W |
| RBSOA | Reverse Bias Safe Operating Area | $T_{j} = 150^{\circ}C$ | 400A @ 600V | |

OUT

NTC2 () NTC1 ()

O

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|---------------|---------------------------------------|---|------------------------|-----|-----|------|------|
| I_{CES} | Zero Gate Voltage Collector Current | $V_{GE} = 0V$ | $T_i = 25$ °C | | | 300 | μA |
| 1CES | Zero Gate Voltage Collector Current | $V_{CE} = 600V$ | $T_{i} = 125^{\circ}C$ | | | 1000 | μА |
| *** | Callantan Emittan action tion Walters | $V_{GE} = 15V$ | $T_j = 25$ °C | | 2.0 | 2.5 | V |
| $V_{CE(sat)}$ | Collector Emitter saturation Voltage | $I_{\rm C} = 180A$ | $T_j = 125$ °C | | 2.2 | | V |
| $V_{GE(th)}$ | Gate Threshold Voltage | $V_{GE} = V_{CE}$, $I_C = 2mA$ | | 3 | | 5 | V |
| I_{GES} | Gate – Emitter Leakage Current | $V_{GE} = 20 \text{ V}, V_{CE} = 0 \text{ V}$ | | | | ±200 | nA |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|------------------|------------------------------|---|----------------|-----|------|-----|------|
| Cies | Input Capacitance | $V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$ | | | 8.6 | | |
| C_{oes} | Output Capacitance | | | | 0.94 | | nF |
| C_{res} | Reverse Transfer Capacitance | | | | 0.8 | | |
| Q_{g} | Total gate Charge | $V_{GS} = 15V$ | | | 660 | | пC |
| Q_{ge} | Gate – Emitter Charge | $V_{\text{Bus}} = 300V$ | | | 580 | | |
| Q_{gc} | Gate – Collector Charge | $I_{\rm C} = 180 A$ | | | 400 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switch | | 26 | | | |
| $T_{\rm r}$ | Rise Time | $V_{GE} = 15V$ | | | 25 | | |
| $T_{d(off)}$ | Turn-off Delay Time | $V_{Bus} = 400V$ $I_{C} = 180A$ | | | 150 | | ns |
| T_{f} | Fall Time | $R_G = 2.5 \Omega$ | | | 30 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switching (125°C) | | | 26 | | |
| $T_{\rm r}$ | Rise Time | $V_{GE} = 15V$ | | | 25 | | |
| $T_{d(off)}$ | Turn-off Delay Time | $I_{C} = 180A$ $R_{G} = 2.5 \Omega$ | | | 170 | | ns |
| $T_{\rm f}$ | Fall Time | | | | 40 | | |
| Eon | Turn-on Switching Energy | $V_{GE} = 15V$ $V_{Bus} = 400V$ | $T_j = 125$ °C | | 8.6 | | |
| E_{off} | Turn-off Switching Energy | $I_C = 180A$ $R_G = 2.5 \Omega$ | $T_j = 125$ °C | | 7 | | mJ |

Reverse diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | Test Conditions | | Тур | Max | Unit |
|-------------------|---|------------------------------|------------------------|-----|------|------|------|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | | 600 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | $V_{R} = 600 V$ | $T_j = 25^{\circ}C$ | | | 750 | μΑ |
| 1RM | | VR OOOV | $T_j = 125$ °C | | | 1500 | μΑ |
| I_F | DC Forward Current | | $T_c = 70$ °C | | 120 | | A |
| | Diode Forward Voltage | $I_F = 120A$ | | | 1.6 | 1.8 | |
| $V_{\rm F}$ | | $I_F = 240A$ | | | 1.9 | | V |
| | | $I_F = 120A$ | $T_j = 125$ °C | | 1.4 | | |
| t_{rr} | Reverse Recovery Time | $I_F = 120A$ $V_R = 400V$ | $T_j = 25$ °C | | 85 | | ns |
| \cdot_{rr} | Reverse Recovery Time | | $T_{j} = 125^{\circ}C$ | | 160 | | 113 |
| Q _{rr} | Reverse Recovery Charge | $di/dt = 800A/\mu s$ | $T_j = 25^{\circ}C$ | | 520 | | nC |
| | | | $T_{j} = 125^{\circ}C$ | | 2800 | | 110 |



Thermal and package characteristics

| Symbol | Characteristic | | | Min | Тур | Max | Unit |
|-------------|---|-------------|-------|------|-----|------|-------|
| P | Junction to Case Thermal Resistance | | IGBT | | | 0.15 | °C/W |
| R_{thJC} | | | Diode | | | 0.32 | C/ VV |
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | | 4000 | | | V |
| T_{J} | Operating junction temperature range | | -40 | | 150 | | |
| T_{STG} | Storage Temperature Range | | -40 | | 125 | °C | |
| $T_{\rm C}$ | Operating Case Temperature | | | -40 | | 100 | |
| Torque | Mounting torque | To Heatsink | M5 | 2.5 | • | 4.7 | N.m |
| Wt | Package Weight | | | • | 160 | g | |

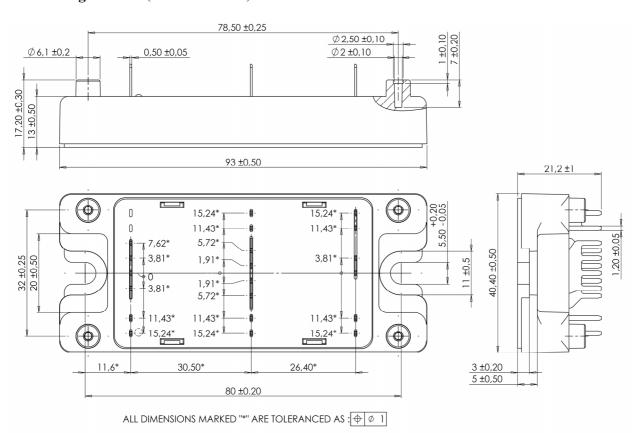
 $Temperature\ sensor\ NTC\ (see\ application\ note\ APT0406\ on\ www.microsemi.com\ for\ more\ information).$

| Symbol | Characteristic | Min | Typ | Max | Unit |
|----------|-----------------------------|-----|------|-----|------|
| R_{25} | Resistance @ 25°C | | 50 | | kΩ |
| B 25/85 | $T_{25} = 298.15 \text{ K}$ | | 3952 | | K |

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

SP4 Package outline (dimensions in mm)

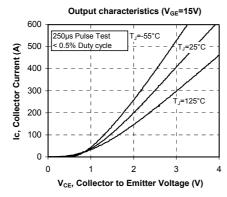


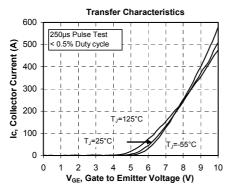
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

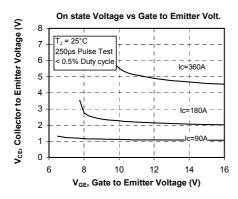
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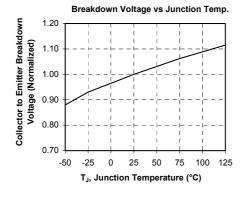


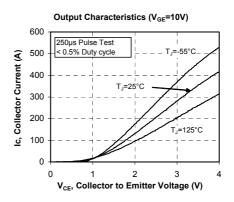
Typical Performance Curve

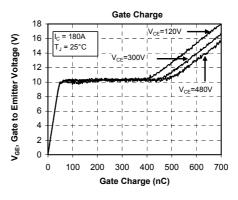


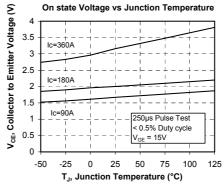


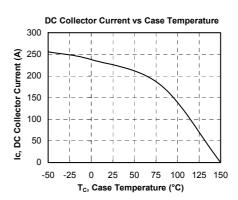






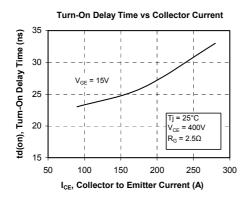


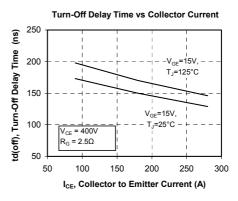


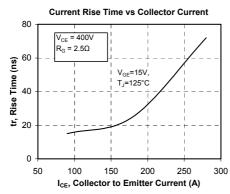


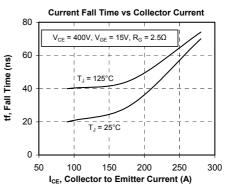
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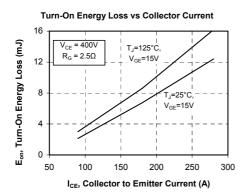


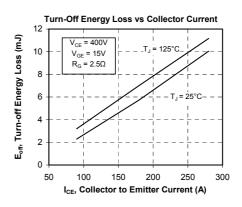


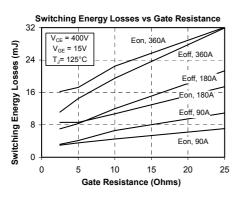


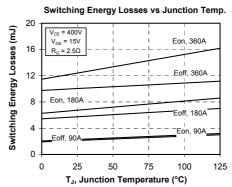




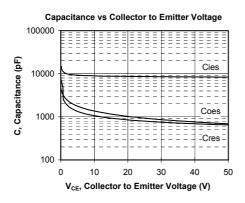


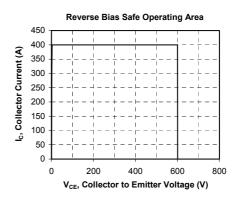


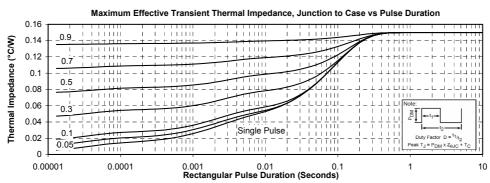




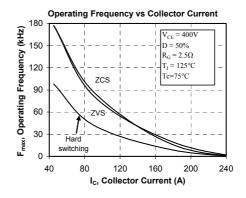








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